Electronic Supplementary Information (ESI)

Multilevel self-organization on anodized aluminium: discovering hierarchical honeycombs from nanometre to sub-millimetre scale

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Fig. S1 Schematic representation of a conventional two-electrode anodizing setup adapted for the manufacturing of the hierarchical macro-/nanotextured aluminium monoliths. The cell is filled with 0.3 M H_2SO_4 aqueous electrolyte solution. Thus, the experiment is conducted under the conditions similar in all respects to previously described by Masuda and Hasegwa apart from the anodizing temperature.¹ For the encapsulation of the sponge-like hierarchical metallic monolith into nanoporous alumina shell, the experiment was suspended, the bath was cooled down from 40 °C to 0 °C, and the experiment was resumed at this low temperature and the same applied voltage of 27 V for another 15 minutes.



Fig. S2 Macroscopic photographs and scanning electron microscopy (SEM) images demonstrating the intermediate stages of aluminium surface evolution towards the hierarchical sponge-like morphology upon anodizing in 0.3 M H_2SO_4 electrolyte at 27 V and 40 °C. The images are taken after 20 min and 2 h of the electrochemical etching (regular-shaped polygonal pores on the upper level of hierarchy were achieved after 4 h of oxidation). After the first 20 minutes (left), the macropore nucleation sites appear on the etched aluminium surface as small craters, but the first 'trumpet-shaped' pores can be already also observed. At the nanoscale level of hierarchy, a steady-state has not been achieved yet, and therefore SEM reveals no hexagonal cell arrangement. After 2 h (right), a system of macropores separated by well-defined ridges can be observed, and the tendency of nanoscale cells towards hexagonal self-ordering also becomes evident.

Electrolyte	Voltage (V)	Temperature (°C)	Pore diameter (nm)	Cell size (nm)	Reference
0.3 M Sulphuric acid (H_2SO_4)	27	0	15-40	63	Masuda <i>et al.</i> , ¹ Asoh <i>et al.</i> ²
0.3 M Oxalic acid (H ₂ C ₂ O ₄)	40	0	67 ± 6 (pores are widened by etching in 5% H ₃ PO ₄ at 30 °C for 90 min.)	99±8	Masuda and Fukuda ³
0.1-3.0 M Selenic acid (H ₂ SeO ₄)	37-51	0	≈ 40	95-110	Kikuchi <i>et al.</i> ⁴
10 wt% Phosphoric acid (H ₃ PO ₄)	160	3	267	420	Li et al. ⁵
0.5-2.0 M Phosphonic acid (H ₃ PO ₃)	150-180	0-20	132 (under optimized conditions: 1.0 M, 150 V and 20 °C)	370-440	Akiya <i>et al.⁶</i>
2-5 M Malonic acid ($CH_2(COOH)_2$)	120	5	-	300	Ono <i>et al.</i> ⁷
3-5 M Tartaric acid (HOOC(CHOH) ₂ COOH)	195	5	-	500	Ono <i>et al.</i> ⁷
0.3 M Tartronic acid (HOOC(CHOH)COOH)	110	0	48±13	222±24	Pashchanka and Schneider ⁸
0.125 M Citric acid ($C_3H_5O(COOH)_3$)	260-450	10-30	230	1100	Mozalev <i>et al.</i> 9
0.3 M Sulphuric acid (H_2SO_4)	27	40	_	450 000 – 900 000; 50- 60 (two superimposed hierarchical textures)	This work

Table S1 Pore and cell size variation ranges and corresponding aluminium anodizing conditions from selected references.

References

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